

Performance Parameters

$$FormFactor = \frac{V_{rms}}{V_{avg}}$$

$$CrestFactor = \frac{V_{peak}}{V_{rms}}$$

$$DistortionFactor = \frac{I_{1rms}}{I_{rms}}$$

ϕ : phase difference between fundamentals of current and voltage

$$DisplacementPowerFactor = \cos(\phi)$$

$$TruePowerFactor = \frac{P}{S} = DPF \frac{I_{1,RMS}}{I_{RMS}}$$

$$THD = \sqrt{\left(\frac{I_{rms}}{I_{1rms}}\right)^2 - 1}$$

Single Phase Diode Rectifier

$$V_{av} = \frac{2\sqrt{2}V_s}{\pi}$$

u : commutation period

$$\cos(u) = 1 - \frac{2\omega L_s I_d}{\sqrt{2}V_s}$$

$$I_{d,avg} = \frac{\int_b^f i(\theta)d\theta}{\pi}$$

$$I_{d,shortcircuit} = \frac{V_s}{\omega L_s}$$

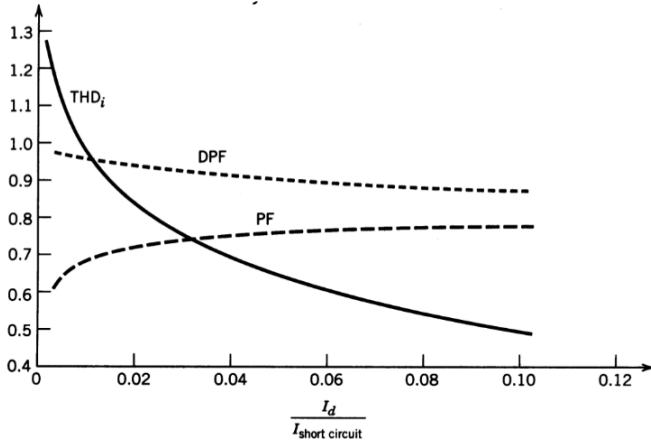


Figure 1: Characteristics of source current wrt wL_s (battery on load side)

Three Phase Rectifier

• Half Wave

$$V_{av} = \frac{3\sqrt{6}V_s}{2\pi}$$

Crossing points (integration) on the waves are from $\pi/6$ to $5\pi/6$

• Full Wave

Full Bridge Rectifier Average Output V_s :rms value of source voltage

$$V_{av} = \frac{3\sqrt{6}V_s}{\pi} - \frac{3\omega L_s I_d}{\pi}$$

Power Semiconductors

Single Phase Controlled Rectifiers-Thyristors

• Idealized Circuit α : firing angle

$$V_{av}(\alpha) = \frac{2\sqrt{2}V_d}{\pi} \cdot \cos \alpha$$

• Effect of L_s

$$\cos(\alpha + u) = \cos(\alpha) - \frac{2\omega L_s I_d}{\sqrt{2}V_s}$$

$$V_d = 0.9V_s \cos(\alpha) - \frac{2\omega L_s I_d}{\pi}$$

Trigonometric

$$\sin A \cos B = \frac{1}{2} [\sin(A - B) + \sin(A + B)]$$

$$\sin A \sin B = \frac{1}{2} [\sin(A - B) - \sin(A + B)]$$

$$\cos A \cos B = \frac{1}{2} [\cos(A - B) + \cos(A + B)]$$

$$\cos A + \cos B = 2 \cos\left(\frac{A+B}{2}\right) \cos\left(\frac{A-B}{2}\right)$$

$$\cos A - \cos B = -2 \sin\left(\frac{A+B}{2}\right) \sin\left(\frac{A-B}{2}\right)$$

$$\sin^2(A) = \frac{1}{2} - \frac{\cos(2A)}{2}$$